

INCHANGE SEMICONDUCTOR

isc N-Channel Mosfet Transistor

BUZ72L

• FEATURES

- Low R_{DS(on)}
- SOA is Power Dissipation Limited
- Nanosecond Switching Speeds
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

DESCRITION

- High current , high speed switching
- Solenoid and relay drivers
- DC-DC & DC-AC converters

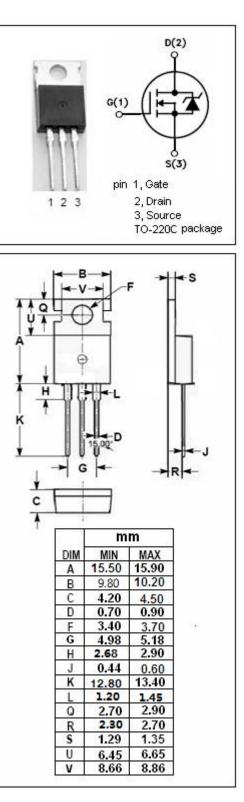
• ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

SYMBOL	ARAMETER	VALUE	UNIT
V _{DSS}	Drain-Source Voltage (V _{GS} =0)	100	V
V _{GS}	Gate-Source Voltage	±20	V
ID	Drain Current-continuous@ TC=25℃	urrent-continuous@ TC=25°C 10	
I _{DM}	Drain Current-Single Plused	40	А
P _{tot}	Total Dissipation@TC=25°C	40	W
Tj	Max. Operating Junction Temperature	150	°C
T _{stg}	Storage Temperature Range	-55~150	°C

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	МАХ	UNIT
R _{th j-c}	Thermal Resistance, Junction to Case	3.1	°C/W
R _{th j-a}	Thermal Resistance, Junction to Ambient	75	°C/W

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ELECTRICAL CHARACTERISTICS

$T_{\text{C}}\text{=}25^{\circ}\!\!\!\!\!\!\mathrm{C}$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYPE	МАХ	UNIT
V _{(BR)DSS}	Drain-Source Breakdown Voltage	V _{GS} = 0; I _D =0.25mA	100			V
V _{GS(th)}	Gate Threshold Voltage	V _{DS} = V _{GS} ; I _D =1mA	1.2		2.0	V
V _{SD}	Diode Forward On-voltage	I _S = 20A ;V _{GS} = 0			1.5	V
R _{DS(on)}	Drain-Source On-Resistance	V _{GS} = 5V; I _D = 5A			0.2	Ω
I _{GSS}	Gate-Body Leakage Current	V _{GS} = ±20V;V _{DS} = 0			±100	nA
IDSS	Zero Gate Voltage Drain Current	V _{DS} =100V; V _{GS} = 0			1	μA
Gfs	Forward Transconductance	V _{DS} = 25V; I _D =5A	5.0			S
t _{d(on)}	Turn-on Delay Time	V _{GS} =5V;			30	
tr	Rise Time	I _D =3A;			130	
t _{d(off)}	Turn-off Delay Time	V _{DD} =30V; R _{GS} =50 Ω			130	ns
t _f	Fall Time				70	

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